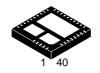
NCP81081

In eg a ed D i e and MOSFET

ON

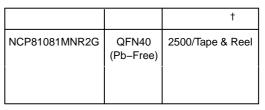
Wh Semiconductor



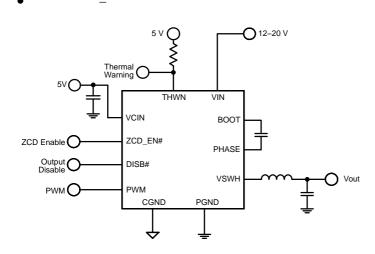


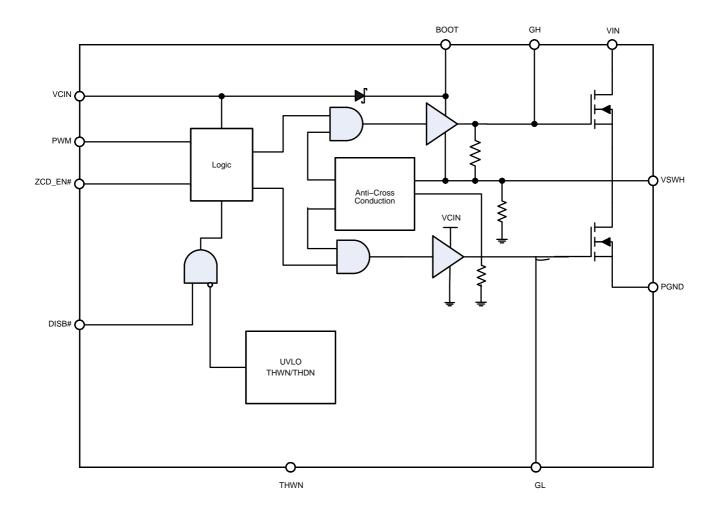
A = Assembly Location

WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb-Free Package



†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.





(Note 1) (VCIN = 5 V, VIN = 12 V, $T_A = -10^{\circ}C$ to +100°C, unless otherwise noted)

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VCIN Current (normal mode)	-	DISB# = 5 V, PWM = OSC, FSW = 400 kHz		14	20	

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QFN40 6x6, 0.5P CASE 485AZ ISSUE O

DATE 09 JAN 2009

